

雷射刻號機 (Laser Marker)

技術資料

Making parameters

- Substrate: Si wafer
- Substrate size: 6 inch
- Ambient: CDA
- Pressure(mbar): 1 atm
- Temperature (C): R.T.
- Laser power: 1.10 W
- Laser pulse rate: 1 KHz
- Making speed: 70 mm/sec